

What is claimed is:

1        1. A dielectric material composition with high  
2 dielectric constant and low dielectric loss, comprising a  
3 metal oxide having a formula of:

4         $Ba_{1-x}M^1_xTi_{1-y}M^2_yO_m$ ,

5        wherein

6         $M^1$  is a metal selected from the group consisting of the  
7 elements of Group IA and IIA of the period table,  
8 lanthanide series, Zn, Bi, and Sn;

9         $M^2$  is a metal selected from the group consisting of Ta,  
10 Zr, Ce, Nb, Co, and Hf;

11        x is a number of 0 to 1;

12        y is a number of 0 to 1; and

13        m satisfies the principle of electrical neutrality for  
14 the metal oxide.

1        2. The composition as claimed in claim 1, wherein  $M^1$  is  
2 Mg, La, or Sr.

1        3. The composition as claimed in claim 2, wherein  $M^1$  is  
2 Sr or La.

1        4. The composition as claimed in claim 1, wherein  $M^2$  is  
2 Ta, Zr, or Hf.

1        5. The composition as claimed in claim 4, wherein  $M^2$  is  
2 Ta.

1        6. The composition as claimed in claim 4, wherein  $M^2$  is  
2 Zr.

1 7. The composition as claimed in claim 4, wherein  $M^2$  is  
2 Hf.

1 8. The composition as claimed in claim 1, wherein  $x$  is a  
2 number of 0 to 0.5.

1 9. The composition as claimed in claim 1, wherein  $y$  is a  
2 number of 0 to 0.5.

1 10. The composition as claimed in claim 1, wherein the  
2 metal oxide is  $(Ba_{1-x}Sr_x)(Ti_{1-y}Ta_y)O_3$ ,  $0.3 \leq x \leq 0.5$ , and  $0 \leq y$   
3  $\leq 0.3$ .

1 11. The composition as claimed in claim 1, wherein the  
2 metal oxide is  $(Ba_{1-x}La_x)(Ti_{1-y}Hf_y)O_3$ ,  $0 \leq x \leq 0.5$ , and  $0 \leq y \leq$   
3  $0.5$ .

1 12. The composition as claimed in claim 1, wherein the  
2 metal oxide is  $(Ba_{1-x}La_x)(Ti_{1-y}Zr_y)O_3$ ,  $0 \leq x \leq 0.5$ , and  $0 \leq y \leq$   
3  $0.5$ .

1 13. The composition as claimed in claim 1, wherein the  
2 dielectric material composition with high dielectric constant  
3 and low dielectric loss is manufactured from a method of  
4 solid state reaction.

1 14. The composition as claimed in claim 1, wherein the  
2 dielectric material composition with high dielectric constant  
3 and low dielectric loss is manufactured from a method of  
4 liquid phase reaction.

1        15. The composition as claimed in claim 1, wherein the  
2 dielectric material composition with high dielectric constant  
3 and low dielectric loss is in a bulk form.

1        16. The composition as claimed in claim 1, wherein the  
2 dielectric material composition with high dielectric constant  
3 and low dielectric loss is in a film form.

1        17. The composition as claimed in claim 1, wherein the  
2 dielectric constant of the dielectric material composition is  
3 more than 320 and the dielectric loss is less than 0.01.

1        18. The composition as claimed in claim 17, wherein the  
2 dielectric constant of the dielectric material composition is  
3 more than 950 and the dielectric loss is less than 0.001.